## NSN 5980-01-349-9924

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5980-01-349-9924

Inclosure	e Material:
Plastic	
Overall L	enath:
	0.260 inches and 0.300 inches
Terminal	Length:
	0.125 inches and 0.145 inches
Overall H	leight:
	0.092 inches and 0.108 inches
Overall V	Vidth:
Between	0.093 inches and 0.099 inches
Lens Tra	nsparency:
Transpare	
-	For Which Designed:
	ht emitting
-	Configuration:
Point con	-
Internal .	Junction Configuration:
Pn	
Mounting	g Method:
Terminal	
Semicon	ductor Material:
Gallium a	rsenide phosphide
Voltage I	Rating In Volts Per Characteristic:
35.0 forw	vard voltage, dc
Current I	Rating Per Characteristic:
35.00 mil	iamperes source cutoff current preset
Power Ra	ating Per Characteristic:
105.0 mil	iwatts small-signal input power, common-collector preset
Color To	ne Produced Per Source:
Yellow lei	าร
Luminou	s Intensity:
1.0 millica	andela
Maximun	n Operating Tempurature Per Measurement Point:
100.0 deg	grees celsius ambient air
Test Data	a Document:
81349-mi	I-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; e	xcludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environm	ental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal	Type And Quantity:
2 pin	
Specifica	ition Data:
81349-mi	I-s-19500/572 government specification
Shelf Life	

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A110a0

